

An exactly solvable lattice model for inhomogeneous interface growth

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We study the dynamics of an exactly solvable lattice model for inhomogeneous interface growth. The interface grows deterministically with constant velocity except along a defect line where the growth process is random. We obtain exact expressions for the average height and height fluctuations as functions of space and time for an initially flat interface. For a given defect strength there is a critical angle between the defect line and the growth direction above which a cusp in the interface develops. In the mapping to polymers in random media this is an example for the transverse Meissner effect. Fluctuations around the mean shape of the interface are Gaussian.

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The problem of nonlinear, KPZ-type interface growth in 1+1 dimensions and the closely related problem of polymers in random media has been the subject of many studies over the past decade [1]. The underlying assumption in this approach is that growth occurs stochastically normal to the interface. The dynamics of the interface are then given by the KPZ equation $\partial_t h = \nu \nabla^2 h + \lambda (\nabla h)^2 + \eta$ [2]. The deterministic version of the equation (without the noise η) can be solved explicitly. Among other things one finds that in the infinite time limit the interface becomes flat. However, in the presence of noise, even an initially flat interface roughens and the derivation of quantities related to the roughening process and other fluctuation phenomena become an interesting and challenging problem, usually tackled using either the renormalization group or the study of lattice models. In this context the asymmetric exclusion process [3], a driven lattice gas model, has played a special role. Both numerical and exact analytical results have been obtained from this microscopically motivated exactly solvable model, which maps to a lattice growth model in the universality class of the noisy KPZ equation.

Recently Kallabis and Lässig studied the KPZ equation with spatially localized noise and found an interesting phase diagram even in one dimension [4]. While this work focussed on the properties of the directed polymer mapping, subsequent work elucidated some properties of the growth model itself [5]. Among other things it was found that in one dimension the interface in the steady state has a cusp with constant slope for arbitrarily small noise. This observation is, in fact, not new: Already some while ago, an exclusion process on a lattice was introduced which mimics the situation of

homogeneous and deterministic growth except along one defect line where growth is stochastic [6]. In the steady state of this non-equilibrium system one finds indeed such a cusp, again for arbitrarily small noise if the defect line is parallel to the average growth direction as assumed in the continuum model studied in Refs. [4, 5]. This makes a study of the dynamical properties of the lattice model desirable. It is the aim of this paper to study the time evolution of an initially flat interface using this model.

The model introduced in Ref. [6] is an exactly solvable version of the deterministic asymmetric exclusion process on a ring with a defect line. We use the well-known RSOS mapping from an interface to a lattice gas [7, 8]: In the interface model the (integer) height variables $h(y, t)$ may differ on neighbouring (integer) sites $y, y+1$ only by ± 1 . As a result of this restriction, growth can occur only in local minima, no overhangs can develop. If a growth event occurs, the height at site y increases by two units (see Fig. 1). In lattice gas language the height differences between neighbouring sites are mapped to a particle occupation number $n_x(t) = 0, 1$ with the presence of a particle on x corresponding to slope -1 between sites $y-1$ and y in the interface model and a vacancy at site x corresponding to slope +1 (see Fig. 1). Growth at site y in the growth model then corresponds to a particle hopping from site x to a vacant site $x+1$. Note that each lattice site can be occupied by at most one particle. In a finite system of $L = 2N$ sites for the particle model one needs N particles in order to ensure periodic boundary conditions in the height model. In an infinite system, an average density $\rho \neq 1/2$ over some finite range L' corresponds to a non-zero average slope $1 - 2\rho$ in that range.

So far this mapping keeps track only of the height differences between

neighbouring sites. In order to make the two models equivalent, one has to introduce an additional integer random variable $h_0 \in \mathbf{Z}$ in the particle system which gives the absolute height of the interface at some arbitrary, but specified point, e.g. $y = 0$. In the lattice gas mapping the value of this random variable is increased by two units each time a particle hops from site 0 to site 1. From this one may reproduce the height at any point since $h(y) = h_0 + \sum_{x=1}^y (1 - 2n_x)$.

The deterministic time evolution is realized by a parallel updating scheme in which in a first step all odd pairs of sites $(2x-1, 2x)$ are updated according to the following rules: If there is a particle on site $2x-1$ and a vacancy on site $2x$, then the particles hop with probability 1 to site $2x$. If the pair of sites is in one of the three remaining configurations, nothing changes. These rules are applied in parallel to all such pairs. In a next step one shifts the pairing by one lattice unit and applies the same rules to the even pairs $(2x, 2x+1)$. This completes one full time step. Note that so far this model is fully deterministic, and any initial configuration will eventually evolve into a flat interface characterized by a particle configuration $(\dots, 1, 0, 1, 0, 1, 0, 1, 0, \dots)$. The dynamical properties of a similar system with slightly different deterministic updating rules were studied in [9].

In order to introduce a defect line at $y = 0$ we change the rules such that a particle on site $x = 0$ hops only with probability $p \leq 1$, if site 1 is vacant. This randomness results in non-trivial behaviour of the system. The stationary properties of this model on a finite ring with N particles were studied in [6] (N arbitrary). Here we shall consider the dynamics of the infinite system with flat initial configuration $(\dots, 1, 0, 1, 0, 1, 0, 1, 0, \dots)$

where the particles are on the odd sites while the vacancies are on the even sites. Because of reflection symmetry one has $h(y) = h(-y)$.

It is useful to note that the time evolution may be written in terms of a transfer matrix $T = pT_0 + (1 - p)T_1$ acting on states corresponding to some given configuration of the system [6]. Any state is fully characterized by the particle occupation numbers n_x and the integer height variable h_0 . T_0 is the transfer matrix for the system without defect, while T_1 is the transfer matrix of the system with full blockage where a particle at site 0 can never move to site 1, even if it is vacant. Acting with T_0 on the state $(\dots, 1, 0, 1, 0, 1, 0, 1, 0, \dots)$ reproduces this state by shifting the whole configuration by two lattice units to the right. This is in accordance with the remark that this configuration is stationary if $p = 1$. The height variable h_0 increases by two units since a particle went from site 0 to site 1. This means that the interface has grown everywhere by two units. On the other hand, the action of T_1 on this state results in a configuration $(\dots, 0, 0, 1, 0, 1, 0, 1, 0, \dots)$ where the first occupation number in this set (which is 0) corresponds to the occupation on site 1. The occupation numbers on site 0 and on the negative sites follow from symmetry. In this case h_0 has not increased, only $h(y)$ for $y \leq 1$ has grown by two units. Taking the t^{th} power of T yields all possible configurations the interface may take after t time steps. Each realization acquires a factor $p^k(1 - p)^{t-k}$ which gives the probability that this particular growth history has taken place.

Using the decomposition of T into T_0 and T_1 it becomes straightforward to calculate the respective probabilities for all these configurations: (1) The odd sublattice remains empty for all times. (2) The consequence of the

defect for the even positive sublattice is the injection of a particle on site 0 with probability p in each time step. (3) If a particle has been injected it will move in each subsequent time step by two lattice units without any interaction with other particles. As an example for what this corresponds to in height language, consider h_0 which we take to be zero at time $t = 0$. With the dynamical rules as explained above one finds after one step $h_0 = 1$ with probability p and $h_0 = 0$ with probability $1 - p$. After two steps one finds $h_0 = 2$ with probability p^2 , $h_0 = 1$ with probability $2p(1 - p)$ and $h_0 = 0$ with probability $(1 - p)^2$, and so on. By construction, the height on the even sublattice will always be even, while on the odd sublattice it will always be odd. Let us denote $h(2y, t) = 2\tilde{h}(2y, t)$. Then one gets for the probability $P_{y,t}(h)$ of finding the height h at site y at time t (for $y \geq 0$)

$$\begin{aligned} P_{2y,t}(h) &= \binom{t-y}{\tilde{h}-y} (1-p)^{t-\tilde{h}} p^{\tilde{h}-y} \quad (0 \leq y \leq t) \\ &= \delta_{\tilde{h},t} \quad (y \geq t) \end{aligned} \tag{1}$$

On the odd (positive) lattice sites one has always, i.e. for all times and all realizations of the randomness, $h(2y-1, t) = h(2y, t) - 1$. For the negative half space $y < 0$ one gets $P[h(-y, t)] = P[h(y, t)]$ by symmetry. This result gives a complete description of the time evolution of the local heights of an interface which is initially (macroscopically) flat.² Note that there are no height fluctuations at all for $y \geq t$. This must be so since the perturbation of the interface caused by the defect spreads with finite velocity $v = 1$ which is the bulk growth velocity.

²Eq. (1) is easy to verify e.g. by applying T two or three times to the initial state. This makes the structure of the interface after t steps already quite clear.

In what follows we study only the non-negative even sublattice up to site $y = t$, since all quantities relating the odd sublattice, the negative half space and the region $y > t$ are then trivially given. From the distribution (1) one obtains the generating function for height fluctuations

$$\begin{aligned}\langle e^{\alpha h(2y,t)} \rangle &= e^{2\alpha y}(1-p + pe^{2\alpha})^{t-y} \quad (0 \leq y \leq t) \\ &= e^{2\alpha t} \quad (y \geq t)\end{aligned}\tag{2}$$

and in particular the average height

$$\begin{aligned}\langle h(2y,t) \rangle &= 2t - 2(1-p)(t-y) \quad (0 \leq y \leq t) \\ &= 2t \quad (y \geq t).\end{aligned}\tag{3}$$

The height fluctuations can be obtained by taking the second logarithmic derivative of the generating function. One finds

$$\begin{aligned}\langle h^2(2y,t) \rangle - \langle h(2y,t) \rangle^2 &= 4p(1-p)(t-y) \quad (0 \leq y \leq t) \\ &= 0 \quad (y \geq t)\end{aligned}\tag{4}$$

From Eq. (3) one finds that the defect causes the development of a cusp with constant slope $2(1-p)$. At site $y = 0$ the interface grows with constant speed $v_0 = 2p$, while in the bulk, at distances larger than t , it grows with velocity $v_b = 2$ (Fig. 2). From (1) one finds that the fluctuations of the interface round its mean value (3) are Gaussian (for t large) with a space-dependent variance given by (4). These are the main results of this paper.

We conclude by briefly discussing the situation in which the defect line is not parallel to the growth direction of the interface. This can be realized within this model by taking a (macroscopically) non-zero initial slope $s =$

$1 - 2\rho$ of the interface. Since growth occurs normal to the interface the net result is indeed a defect line tilted relative to the main growth direction. In particle language one has to choose an initial state with a density $\rho \neq 1/2$, e.g. a configuration $(\dots, 1, 0, 0, 0, 1, 0, 0, 0, \dots)$. From the analysis of the steady state of this system one finds that a phase transition takes place at $p_c = 2\rho$ for $\rho \leq 1/2$ (positive initial slope) and $p_c = 2(1 - \rho)$ for $\rho \geq 1/2$ (negative initial slope) respectively [6]. For the dynamics of an initially flat interface the steady state properties of the system suggest that for $p > p_c$ the interface remains flat for all times except in a finite region close to the defect. For $p < p_c$ a cusp will evolve. Unlike in the situation described above, the boundary of this cusp will not be sharp, but fluctuate. In a finite system these fluctuations scale in the system size like $L^{1/2}$ and one would therefore expect a power growth $t^{1/2}$ in time of these domain boundary fluctuations in the infinite system. For fixed p this is a phase transition that takes place at critical slopes $s_c = \pm(1 - p)$. For $-(1 - p) \leq s \leq (1 - p)$ the system develops the cusp.

This situation is also of interest in the well-known mapping of this problem to a directed polymer in a medium with a random defect line, as studied in Ref. [4] for the special case $\rho = 1/2$ where the defect line and the average direction of the polymer are parallel. The development of the cusp corresponds to having a bound state where the polymer is bound to the (attractive) defect line. It is no surprise that this happens at arbitrarily small defect strength. This simply reflects the fact that in one dimension a delta function potential (the defect line) with arbitrarily small amplitude has a bound state. Translated into polymer language the phase transition in the

interface model is a transition from an bound state of the polymer for a tilt of the defect line against the (average) direction of the polymer below the critical angle s_c to an unbound state for a tilt above s_c . This is a simple example for the occurrence of the transverse Meissner effect [10].

A macroscopic cusp with constant slope appears to be an universal feature of growth models with a defect line where the growth process is impeded. In this sense some features of the model studied in this paper may be of more than purely theoretical interest. Normal growth, which is the underlying assumption that leads to the KPZ equation, has been reported to occur e.g. in experiments on wetting of tapes plunged in a liquid [11]. It would therefore be interesting to adapt the model to this situation by an appropriate choice of boundary conditions. On the other hand, our simple model has some clear limitations. The strict discontinuity of the slope of the interface at $y = t$ (for the half-filled system) is obviously an artefact of the dynamics chosen here and cannot be expected to be found in any real system. One would rather expect a smeared out discontinuity as in the system with a tilted defect or as in the fully stochastic version of the model with a defect [12]. Another, intrinsic, limitation of the model is that growth at the defect is always slower than in the bulk. It would be very interesting to study a model where the defect growth could be made faster than the bulk growth velocity.

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List of Figure Captions

Fig. 1: The mapping between the restricted interface and the particle exclusion process: we show a possible interface configuration and the corresponding particle occupancies on a lattice with sites labeled by y . The indicated flips in the interface correspond to particles hopping on the lattice, marked by horizontal arrows.

Fig. 2: Macroscopic average interface shape at time $t = 0$ (flat interface with height 0) and at some later time t . The position of the defect at $y = 0$ is indicated by the vertical dashed line. The defect line is parallel to the bulk growth direction.

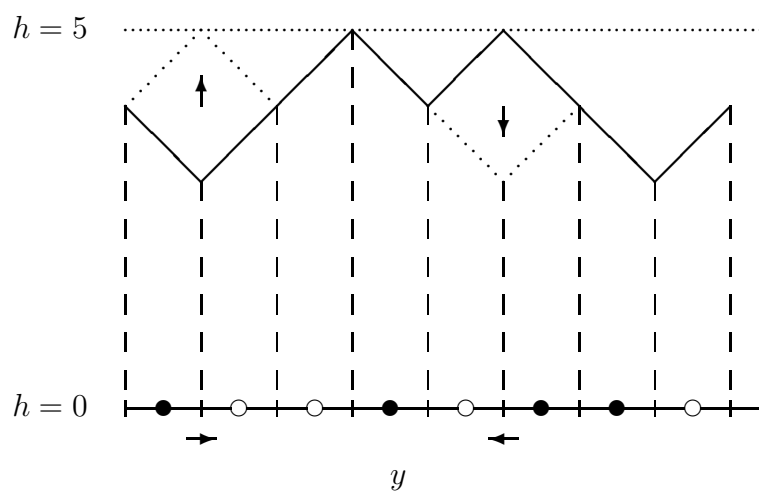


Figure 1:

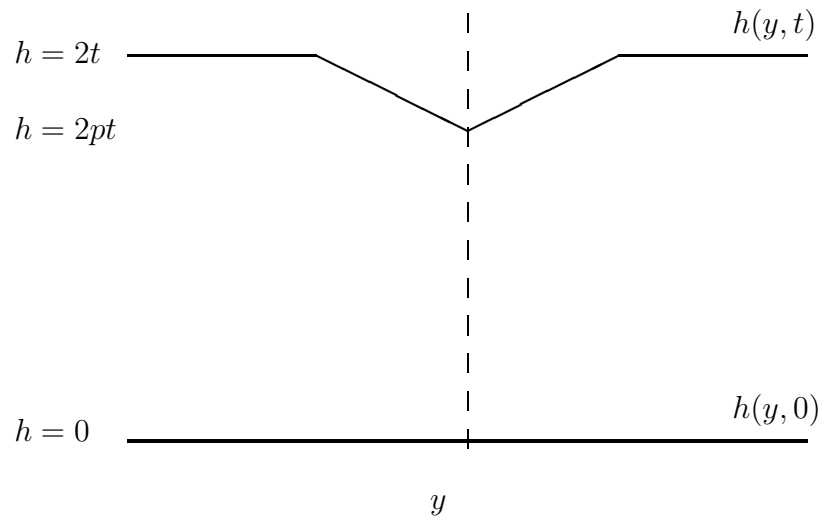


Figure 2: